

DMN2008LFU-7

DMN2008LFU-7 Information

www.nelsens.com	 DMN2008LFU-7 Diodes Incorporated Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CHA 20V 14.5A DFN2030 6-UFDFN Exposed Pad For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



DMN2008LFU-7 Specifications

Manufacturer Part Number	DMN2008LFU-7
Manufacturer	Diodes Incorporated
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	6-UFDFN Exposed Pad
Series	-
FET Type	2 N-Channel (Dual)
FET Feature	Standard
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	14.5A
Rds On (Max) @ Id, Vgs	5.4 mOhm @ 5.5A, 4.5V
Vgs(th) (Max) @ Id	1.5V @ 250A
Gate Charge (Qg) (Max) @ Vgs	42.3nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1418pF @ 10V
Power - Max	1W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-UFDFN Exposed Pad
Supplier Device Package	U-DFN2030-6 (Type B)
	Report errors?

DMN2008LFU-7 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DMN2008LFU-7 Payment Methods



DMN2008LFU-7 Shipping Methods



If you have any question about DMN2008LFU-7, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com